

2SC1775A

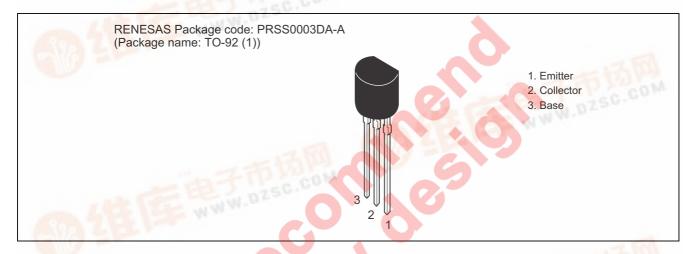
Silicon NPN Epitaxial

REJ03G0690-0300 (Previous ADE-208-1056) Rev.3.00 Mar 03, 2006

Application

- Low frequency low noise amplifier
- Complementary pair with 2SA872A

Outline



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Rating	Unit	
Collector to base voltage	V _{CBO}	120	V	
Collector to emitter voltage	V _{CEO}	120	V	
Emitter to base voltage	V_{EBO}	5	V	
Collector current	l _C	50	mA	
Collector power dissipation	P _C	300	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-50 to +150	°C	
		@维库。	WW.DZSG.	

Electrical Characteristics

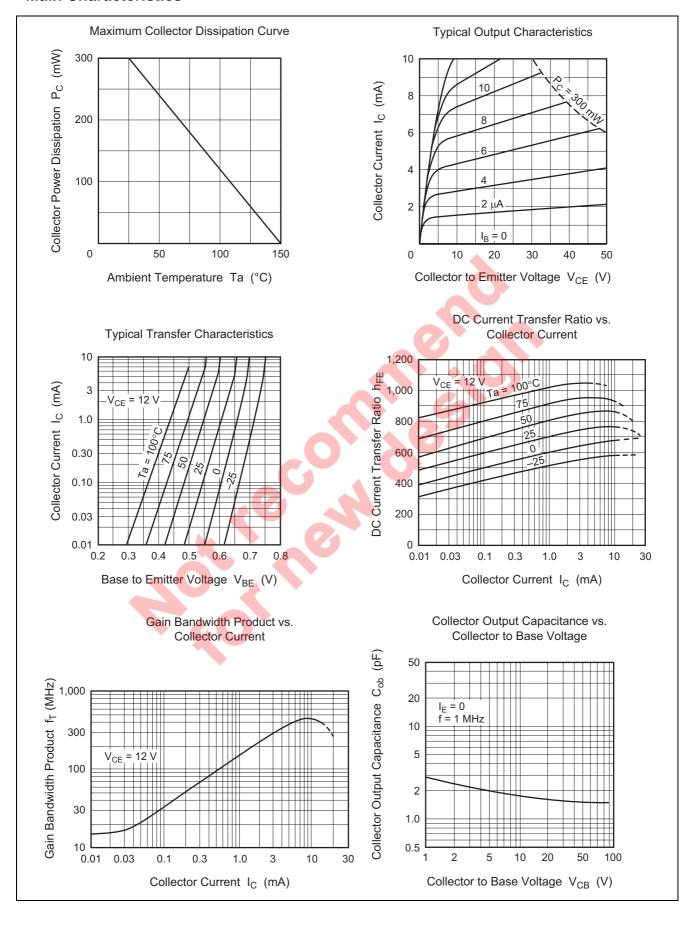
 $(Ta = 25^{\circ}C)$

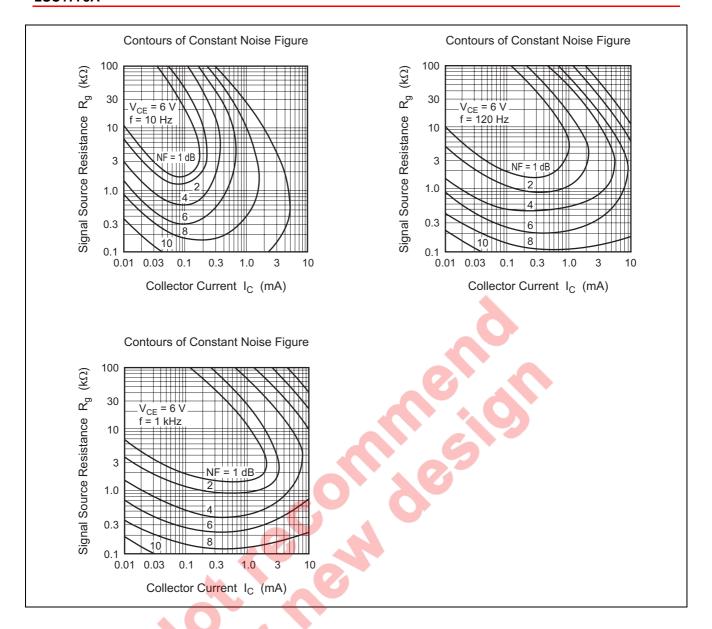
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown	V _{(BR)CEO}	120	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
voltage						
Collector cutoff current	I _{CBO}	_	_	0.5	μΑ	$V_{CB} = 100 \text{ V}, I_{E} = 0$
DC current transfer ratio	h _{FE1} *1	400	_	1200		$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
	h _{FE2}	160	_	_		$V_{CE} = 12 \text{ V}, I_{C} = 0.1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	_	0.75	V	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector to emitter saturation	V _{CE(sat)}	_	_	0.5	V	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
voltage						
Gain bandwidth product	f _T	_	200	_	MHz	$V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}$
Collector output capacitance	Cob	_	1.6	_	pF	$V_{CB} = 25 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Noise figure	NF	_	_	5.0	dB	$V_{CE} = 6 \text{ V}, I_{C} = 50 \mu\text{A}, f = 10 \text{ Hz}$
		_	_	1.5	dB	$R_g = 50 \text{ k}\Omega$ $f = 1 \text{ kHz}$

Note: 1. The 2SC1775A is grouped by h_{FE1} as follows.

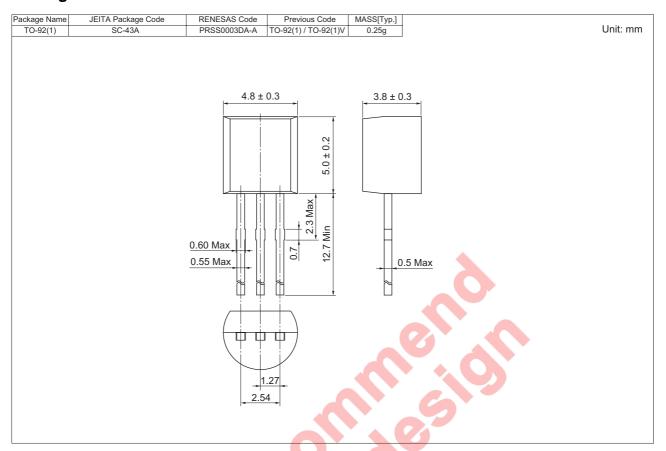
ш	F	
400 to 800	600 to 1200	

Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC1775AETZ	2500	Hold Box, Radial Taping
2SC1775AFTZ		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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